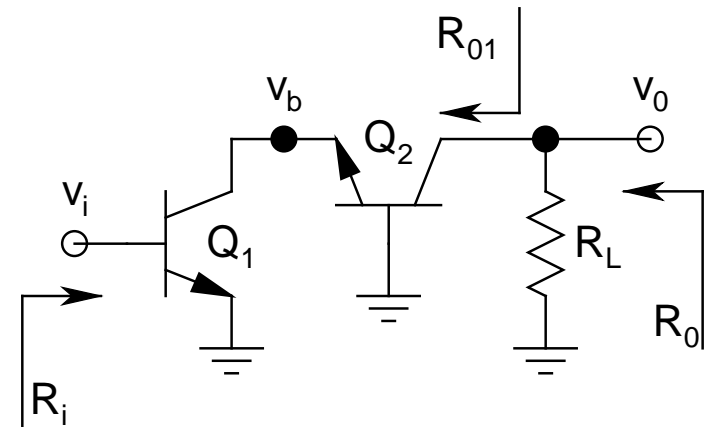


- *npn Cascode:*

- *CE*, followed by *CB*
- Known as *Wideband Amplifier*, due to its *superior frequency response characteristic*



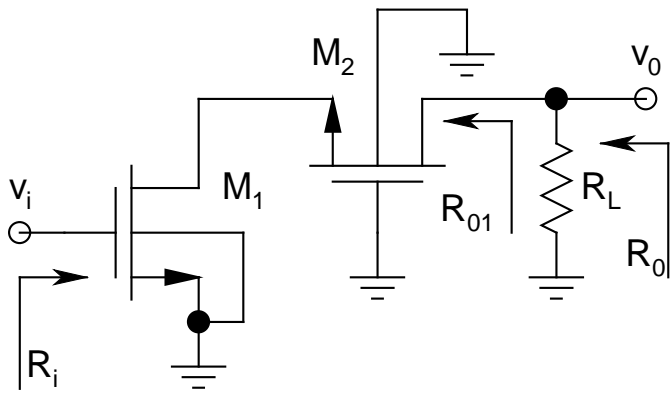
ac Schematic

- *Generally, both Q_1 and Q_2 are biased with the same I_C*
- *Assuming Q_1 - Q_2 have same β :*

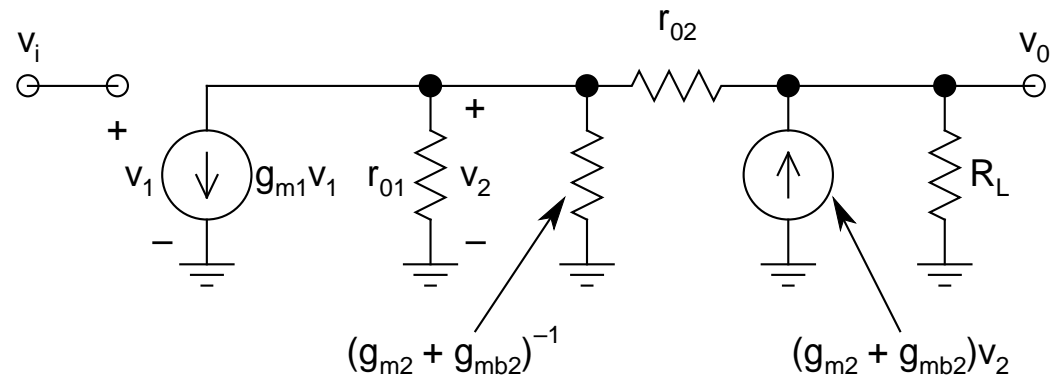
$$r_{E1} = r_{E2} = r_E \text{ and } r_{\pi1} = r_{\pi2} = r_{\pi}$$

- $R_0 = R_L || R_{01}$
- *If r_0 is neglected*, then $R_{01} \rightarrow \infty$
- *If r_0 is included*, then $R_{01} = \beta r_{02}$ (*very high*)
- However, *it comes in parallel with R_L*
 \Rightarrow *Overall R_0 is still $\sim R_L$*
- *Summary:*
 - *Moderate voltage gain*
 - *Moderate input resistance*
 - *Potential of having very large output resistance*
 - *Extremely large bandwidth*
 - *Preferred over a simple CE stage*

- ***NMOS Cascode:***



ac Schematic



ac Midband Equivalent

- ***CS***, followed by ***CG***
- ***Generally, both M_1 and M_2 are biased with the same I_D***
- ***M_1 does not have body effect, but M_2 has***

- *By inspection*, $R_i \rightarrow \infty$ and $R_0 = R_L || R_{01}$
- *With r_{02} present, the analysis becomes a little complicated \Rightarrow neglect $r_{02} \Rightarrow R_0 = R_L$*
- *Neglecting r_{02} :*

$$v_0 = (g_{m2} + g_{mb2})v_2 R_L$$

$$v_2 = -g_{m1}v_1 / (g_{m2} + g_{mb2} + g_{01}) \quad (g_{01} = 1/r_{01})$$

$$\approx -g_{m1}v_1 / (g_{m2} + g_{mb2})$$

[since, in general, $g_{01} \ll (g_{m2} + g_{mb2})$]

$$\Rightarrow A_v = v_0/v_i = -g_{m1}R_L \quad (\text{since } v_1 = v_i)$$
- *This is same as the CS stage, however, here broad-banding is happening!*